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09/659,872	09/13/2000	Hartmund Terletzki	00P7882US	7001

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EXAMINER

NGUYEN, MINH T

ART UNIT	PAPER NUMBER
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2816

DATE MAILED: 01/07/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

## Office Action Summary

**Application No.**

09/659,872

**Applicant(s)**

TERLETZKI ET AL.

**Examiner**

Minh Nguyen

**Art Unit**

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

### Status

- 1) ☒ Responsive to communication(s) filed on 30 October 2003.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

### Disposition of Claims

- 4) ☒ Claim(s) 2-30 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☒ Claim(s) 2-8 and 10-14 is/are allowed.
- 6) ☒ Claim(s) 9,15,18,20-28 and 30 is/are rejected.
- 7) ☒ Claim(s) 16,17,19 and 29 is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

### Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 12 April 2002 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

### Priority under 35 U.S.C. §§ 119 and 120

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some \* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
  2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.
- 13) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application) since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.
- a) ☐ The translation of the foreign language provisional application has been received.
- 14) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121 since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.

### Attachment(s)

- 1) ☐ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO-1449) Paper No(s) \_\_\_\_\_.
- 4) ☐ Interview Summary (PTO-413) Paper No(s). \_\_\_\_\_.
- 5) ☐ Notice of Informal Patent Application (PTO-152)
- 6) ☐ Other: \_\_\_\_\_.

## **DETAILED ACTION**

### ***Continued Examination Under 37 CFR 1.114***

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 10/30/03 has been entered.

2. Claims 2-30 are pending. The following is a detailed Office action.

### ***Claim Objections***

3. Claims 9 and 21 are objected to because of the following informalities:

In claim 9, line 2, "a first reference voltage node carrying" should be deleted because this node does not have any structural relationship with any other elements in the circuit, i.e., the present of this node would create the lack of structural relationship problem,

line 6, "different that the first voltage level" should be changed to -- different than the first voltage level --.

In claim 21, line 2, "levels", first occurrence, should be changed to -- level --.

Appropriate correction is required.

***Claim Rejections - 35 USC § 102***

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 9, 15, 18, 20-27 and 30 are rejected under 35 U.S.C. 102(b) as being anticipated by US Patent No. 6,181,165, issued to Hanson et al. (a copy of the reference is not provided because it is listed in the IDS (PTO-1449)).

Note that the rejections are based on Fig. 1 which is prior art, and Fig. 1 is known before the filing date (March 9, 1998).

As per claim 9, Hanson discloses a level shifting circuit (Fig. 1), comprising:

a first reference node carrying a first voltage level (about 1V, reduced voltage, column 2, lines 18-20);

a second reference voltage node carrying a second voltage level (ground, column 1, line 40), clearly ground is different from 1V;

a third reference node carrying a third voltage level (VDD), it is clear that VDD is different than ground or 1V;

an input node to receive an input signal (IN), the input signal varying between the first voltage level and a second voltage level (from 1V to ground);

a first n-channel transistor (106) having a first source/drain region, a second source/drain region and a gate, the gate being coupled to the input node (IN);

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a second n-channel transistor (108) having a first source/drain region coupled to the second source/drain region of the first n-channel transistor, a second source/drain region coupled to a second voltage level reference node (ground) and a gate coupled to a first enable signal node (ENABLE);

a first p-channel transistor (104) having a first source/drain region coupled to the first source/drain region of the first n-channel transistor, a second source/drain region and a gate coupled to the input node (IN);

a second p-channel transistor (102) having a first source/drain region coupled to the second source/drain region of the first p-channel transistor, a second source/drain region coupled to a third reference node (VDD) and a gate coupled to a second enable signal node (ENABLEN).

As per claim 15, the recited limitation is disclosed in column 1, lines 29-30.

As per claim 18, it is clear that the third voltage level (VDD) is greater than the first voltage level (1V, reduced voltage).

As per claim 20, Hansen discloses a level shifting circuit (Fig. 1) comprising:

a level-shifting section (FETs 104 and 106) responsive to an input logic signal (IN), the input logic signal varying between a first voltage level (ground) and a second voltage level (1V, reduced voltage, column 2, lines 18-19), the level-shifting section providing an output logic signal (OUT), the output logic signal varying between the first voltage level (ground) and a third voltage level (VDD), the third voltage level being different than the second voltage level (VDD > 1V);

a first reference voltage node carrying a voltage at the first voltage level (ground);

a third reference voltage node carrying a the third voltage level (VDD); and

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an enable/disable section (FETs 102 and 108) including a first portion (FET 108) coupled between the level shifting section and the first reference voltage node (ground) and a second portion (FET 102) coupled between the level shifting section and the third reference voltage node (VDD), the enable/disable section being responsive to an enable/disable signal (ENABLE/ENABLEN), the enable/disable section causing the output terminal to be placed at a relatively high output impedance condition independent of the logic state of the input logic signal in response to a disable mode indication from the enable/disable signal (column 1, lines 30-33, tri-state).

As per claim 21, VDD or 1V represent logic "HI" and ground represents logic "LOW".

As per claim 22, the recited first transistor reads on FET 104 and the recited second transistor reads on FET 106.

As per claim 23, the recited third transistor reads on FET 102 and the recited fourth transistor reads on FET 108.

As per claim 24, disclosed in column 1, lines 29-33.

As per claim 25, the recited first switch reads on FET 108 and the recited second switch reads on FET 102.

As per claims 26-27, since ENABLEN is inverted of ENABLE (column 1, lines 29-30), the recited limitations are inherently met.

As per claim 30, (102) and (108) are MOS transistors.

***Claim Rejections - 35 USC § 103***

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5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claim 28 is rejected under 35 U.S.C. 103(a) as being unpatentable over US Patent No. 6,181,165, issued to Hanson et al.

Hanson discloses a level shifting circuit having the structure discussed in claim 26 but he does not explicitly disclose the inverter is powered by the power supply voltage VDD.

As known by a person skilled in the art, the inverter in the Hanson circuit can be powered by the VDD or the reduced voltage, and using VDD to power the inverter, FETs 102 and 108 can be functioned more like switches because smaller voltage drop across the drain and source of the FETs, i.e., recall the basis operation of a FET, when a FET is used as a switch, the FET should be operated in saturation mode.

It would have been obvious to one skilled in the art at the time of the invention was made to power the inverter using VDD voltage instead of the reduced voltage to improve the output swing of the OUT signals.

### ***Response to Arguments***

6. Applicant's arguments with respect to the claims have been considered but are moot in view of the new ground(s) of rejection.

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*Allowable Subject Matter*

7. Claims 2-8 and 10-14 are allowed for the reasons noted in the previous Office actions.

8. Claims 16-17, 19 and 29 would be allowable if rewritten to overcome the rejection(s) under 35 U.S.C. 112, second paragraph, set forth in this Office action and to include all of the limitations of the base claim and any intervening claims.

Claims 16-17 and 19 are allowable because the prior art of record fails to disclose or suggest the inclusion of a level shifter in the inverter circuit as recited in claim 16.

Claim 29 is allowable for the same reason noted in claim 16.

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Minh Nguyen whose telephone number is 703-306-9179. The examiner can normally be reached on Monday, Tuesday, Thursday, Friday 7:00-5:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy Callahan can be reached on 703-308-4876. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9318.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.



1/6/04

Minh Nguyen  
Primary Examiner  
Art Unit 2816